Red Laser Diode



Overview

DL-3148-021 is 635 nm (Typ.) index guided AlGaInP laser diode with low threshold current. The low threshold current and short wavelength are achieved by the use of a strained multiple quantum well active layer. The lasing wavelength is the same as that of the He-Ne gas laser. DL-3148-021 is suitable for applications such as laser pointers.

Features

- Short wavelength
- Low threshold current

: 635 nm (Typ.) : Ith = 30 mA (Typ.) : 3 mW CW

- Output powerSmall package
- : 3 mW CW : 5.6 mm φ
- Absolute Maximum Ratings at Tc=25°C

Parameter		Symbol	Ratings	Unit	
Light Output		Ро	3	mW	
Reverse Voltage	Laser	VR	2	V	
	PIN	ΥK	30		
Operating Temperature		Topr	-10 to +40	°C	
Storage Temperature		Tstg	-40 to +85	°C	

Electrical and Optical Characteristics at Tc=25 °C

Para	neter	Symbol	Condition	Min.	Тур.	Max.	Unit
Threshold	d Current	Ith	CW	-	30	50	mA
Operating	g Current	Iop	Po=3mW	_	35	55	mA
Operating	g Voltage	Vop	Po=3mW	-	2.2	2.4	V
Lasing W	avelength	λp	Po=3mW	-	635	640	nm
Beam 💥)	Perpendicular	$\theta \perp$	Po=3mW	25	35	40	deg.
Divergence	Parallel	θ //	Po=3mW	6	8	10	deg.
Off Axis	Perpendicular	$\Delta \theta \perp$	-	_	-	±3	deg.
Angle	Parallel	$\Delta heta$ //	-	-	-	±3	deg.
Differential	Efficiency	dPo/dIop	-	-	0.5	-	mW/mA
Monitoring O	utput Current	Im	Po=3mW	0.03	0.1	_	mA
Astign	natism	As	Po=3mW	-	10	_	μm

※) Full angle at half maximum note : The above product specifications are subject to change without notice.

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Package Dimensions



Electrical Connection







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Precautionary instructions in handling gallium arsenic products

Special precautions must be taken in handling this product because it contains, gallium arsenic, which is designated as a toxic substance by law. Be sure to adhere strictly to all applicable laws and regulations enacted for this substance, particularly when it comes to disposal.

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